U.S. PTO 12/927947 11/30/2010

Form PTO-1595 (Rev 03-09) U.S. DEPARTMENT OF COMMERCE OMB No 0651-0027 (exp 03/31/2009) 12-10-2010 United States Patent and Trademark Office 103613297 To the Director of the U.S. Patent and cuments or the new address(es) below 1. Name of conveying party(ies) 2. Name and address of receiving party(ies) Name: National Semiconductor Corporation Jamal Ramdani Internal Address: Additional name(s) of conveying party(ies) attached? Yes X No 3. Nature of conveyance/Execution Date(s): Street Address: 2900 Semiconductor Drive Execution Date(s) November 29, 2010 X Assignment Merger City: Santa Clara Security Agreement Change of Name Joint Research Agreement State: California Government Interest Assignment Country: U.S.A **Zip**. 95051 Executive Order 9424, Confirmatory License Other_ Additional name(s) & address(es) attached? Yes X No 4. Application or patent number(s): This document is being filed together with a new application A. Patent Application No (s) B. Patent No.(s) Additional numbers attached? 5. Name and address to whom correspondence 6. Total number of applications and patents concerning document should be mailed: involved: Name ________Docket Clerk 7. Total fee (37 CFR 1 21(h) & 3.41) \$__40.00 Internal Address P.O. Drawer 800889 X Authorized to be charged to deposit account Street Address _____ X Enclosed None required (government interest not affecting title) 8. Payment Information City Dallas State:____tx__ Phone Number. (972) 628-3600 Deposit Account Number 50-0208 Fax Number (972) 628-3616 Authorized User Name William A. Munck Email Address:_ 9. Signature: November 30, 2010 Signature Date William A. Munck Registration No. 39,308 Total number of pages including cover Name of Person Signing sheet, attachments, and documents:

	Sample Form (former PTO/SB/15) (08-0
ASSIGNMENT OF APPLICATION	Docket Number (Optional) P07491
Whereas, I/We, Jamal Ramdani of Scarborough,	Maine , hereafter
referred to as applicant, have invented certain new and useful improvements in STRESS COMPENSATION FOR LARGE AREA GALLIUM NITRIDE OR OTHER NITRIDE-BASED STRUCTURES ON SEMICONDUCTOR SUBSTRATES	
for which an application for a United States Patent was filed on	
Application Number	
for which an application for a United States Patent was executed on	, and
Whereas, National Semiconductor Corporation of Santa Clara, California	here referred
to "assignee" whose mailing address is 2900 Semiconductor Drive, Santa Clar	ra, Califomia 95051 is
desirous of acquiring the entire right, title and interest in the same;	
acknowledge, and other good and valuable consideration, I/We, the applicant and transfer unto said assignee the full and exclusive right to the said invention rights, title and interest in and to any and all Patents which may be granted thereby authorize and request the Director of the U.S. Patent and Trademark Patent to said assignee, of the entire right, title, and interest in and to the same for the use and behoof of his legal representatives, to the full end of the transfer granted, as fully and entirely as the same would have been held by me had made. Executed this	n in the United States and the entire therefore in the United States. I/Wid Office to issue said United States no, for his sole use and behoof; and erm for which said Patent may be this assignment and sale not beer
State of Main 2) Jam	ignature nal Ramdani gistration No., if applicable
Before me personally appeared saidJamal Ramdani	
and acknowledged the foregoing instrument to be his free act and deed this	29 #
day of November, 20 10	ANITA T. HAMPTON Notary Public
Seal	Maine Commission Expires May 26, 2012
Note: Signatures of all the inventors or assignees of record of the entire interest of their representations than one signature is required. See below.	tive(s) are required. Submit multiple forms if

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forms are submitted.

REEL: 025465 FRAME: 0002

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